

# Continental Device India Limited

An ISO/TS 16949, ISO 9001 and ISO 14001 Certified Company





# **SOT-23 Formed SMD Package**

# CMBTA55 CMBTA56

# SILICON EPITAXIAL TRANSISTORS

P-N-P transistor

Marking

CMBTA55 = 2H

CMBTA56 = 2G

PACKAGE OUTLINE DETAILS
ALL DIMENSIONS IN mm

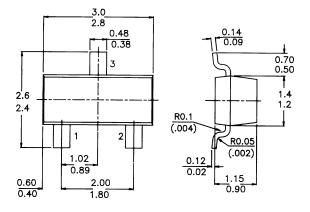


1 = BASE

2 = EMITTER

3 = COLLECTOR





#### ABSOLUTE MAXIMUM RATINGS

		СМВТ	'A55		<u> </u>	
Collector-base voltage (open emitter)	$-V_{CBO}$	max.	60		80	V
Collector-emitter voltage (open base)	$-V_{CEO}$	max.	60		80	V
Emitter-base voltage (open collector)	$-V_{EBO}$	max.		4	V	
Collector current (d.c.)	$-I_C$	max.		<i>500</i>		mΑ
Total power dissipation up to $T_{amb} = 25$ °C	$P_{tot}$			<i>250</i>		mW
D.C. current gain						
$-I_C = 100 \text{ mA; } -V_{CE} = 1 \text{ V}$	$h_{FE}$	min.		100		
Transition frequency at $f = 100 \text{ MHz}$						
$-I_C = 100 \text{ mA; } -V_{CE} = 1 \text{ V}$	$f_T$	min.		<i>50</i>		MHz
Collector-emitter saturation voltage						
$-I_C = 100 \text{ mA}; I_B = 10 \text{ mA}$	$V_{CEsat}$	max.		0.25		V

# CMBTA55 CMBTA56

# **RATINGS** (at $T_A = 25^{\circ}C$ unless otherwise specified) Limiting values

		CMBT .	A55	A56	A56	
Collector-base voltage (open emitter)	$-V_{CBO}$	max.	60	80	V	
Collector-emitter voltage (open base)	$-V_{CEO}$	max.	60	80	V	
Emitter-base voltage (open collector)	$-V_{EBO}$	max.		4	V	
Collector current (d.c.)	$-I_C$	max.	5	00	mA	
Total power dissipation up to $T_{amb} = 25  {}^{\circ}C$	$P_{tot}$	max.	2	50	mW	
Storage temperature	$T_{Stg}$		−55 t	o +150	$^{\circ}$ $C$	
Junction temperature	$T_{i}$	max.	1	<i>50</i>	$^{\circ}$ $C$	

# THERMAL CHARACTERISTICS

 $T_j = P \ (R_{th \ j-t} + R_{th \ t-s} + R_{th \ s-a}) + T_{amb}$  Thermal resistance from junction to ambient  $R_{th \ j-a}$  500 K/W

# **CHARACTERISTICS** (at $T_A = 25^{\circ}C$ unless otherwise specified)

Collector–emitter breakdown voltage	so otherwise spe		CMBTA 55		A56	3
$-I_C = 1 \text{ mA}; I_B = 0$	$-V_{(BR)CE}$	Omin.	60		80	V
Emitter-base breakdown voltage						
$-I_C = 0$ ; $I_E = 100  \mu A$	$-V_{(BR)EBO}$	$-V_{(BR)EBO}$ min.		4		V
Collector cut-off current	, ,					
$-V_{CE} = 60 \ V; I_B = 0$	$-I_{CEO}$	max.		0.1		$\mu A$
$-V_{CB} = 60 \text{ V; } I_E = 0$	$-I_{CBO}$	max.	0.1		-	$\mu A$
$-V_{CB} = 80 \ V; I_{E} = 0$	$-I_{CBO}$	max.			0.1	$\mu A$
Saturation voltages						
$-I_C = 100 \text{ mA}; -I_B = 10 \text{ mA}$	-V <sub>CEsat</sub>	max.		0.25		V
Base-emitter On voltage						
$-I_C = 100 \text{ mA; } -V_{CE} = 1 \text{ V}$	$-V_{BE(on)}$	max.		1.2		V
D.C. current gain	, ,					
$-I_C = 10 \text{ mA; } -V_{CE} = 1 \text{ V}$	$h_{FE}$	min.		100		
$-I_C = 100 \text{ mA; } -V_{CE} = 1 \text{ V}$	$h_{FE}$	min.		100		
Transition frequency at $f = 100 \text{ MHz}$						
$-I_C = 100 \text{ mA; } -V_{CE} = 1 \text{ V}$	$f_T$	min.		<i>50</i>		MHz

# **Customer Notes**

### **Disclaimer**

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